MAGNETIC MEMORY HAVING ANGLED THIRD CONDUCTOR

Abstract of the Disclosure

One embodiment of a magnetic memory includes a magnetic memory stack and a first line adjacent the magnetic memory stack. A second line crosses the first line, and a third line crosses the first line and the second line. The third line is angled relative to the first line and the second line, where the first line, the second line and the third line are configured to produce magnetic fields that set states of the magnetic memory stack.